# Photointerrupter, Ultraminiature SMD type

RPI-0125 Datasheet

#### Applications

- DSC(Digital steal camera)
- DVC(Digital video camera)

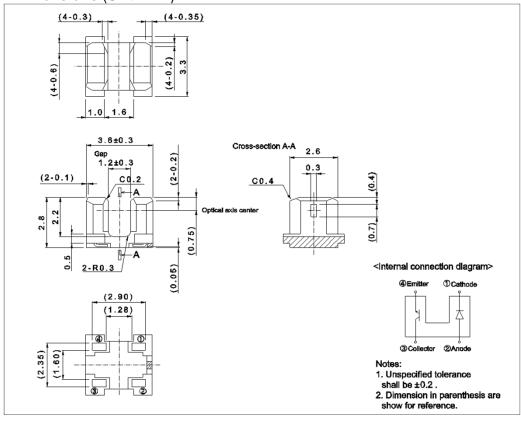
#### Features

- 1) Ultra-small.
- 2) Gap 1.2mm.





#### ● Dimensions (Unit: mm)



### ● Absolute maximum ratings (T<sub>a</sub> = 25°C)

| Parameter                        |                             | Symbol           | Value         | Unit |  |
|----------------------------------|-----------------------------|------------------|---------------|------|--|
| Input (LED)                      | Forward current             | I <sub>F</sub>   | 50            | mA   |  |
|                                  | Reverse voltage             | $V_R$            | 5             | V    |  |
|                                  | Power dissipation           | $P_{D}$          | 80            | mW   |  |
| Output<br>(photo-<br>transistor) | Collector-emitter voltage   | V <sub>CEO</sub> | 30            | V    |  |
|                                  | Emitter-collector voltage   | V <sub>ECO</sub> | 4.5           | V    |  |
|                                  | Collector current           | I <sub>C</sub>   | 30            | mA   |  |
|                                  | Collector power dissipation | P <sub>C</sub>   | 80            | mW   |  |
| Operating temp                   | perating temperature        |                  | -25 to +85    | °C   |  |
| Storage temper                   | rature                      | $T_{stg}$        | −30 to +85 °C |      |  |

# ●Electrical and optical characteristics (T<sub>a</sub> = 25°C)

| Parameter                    |                                      |           | Symbol               | Conditions   | Values |      |      | 1.126 |
|------------------------------|--------------------------------------|-----------|----------------------|--|--------|------|------|-------|
|                              |                                      |           |                      |  | Min.   | Тур. | Max. | Unit  |
| Input characteristics        | Forward voltage                      |           | V <sub>F</sub>       | I <sub>F</sub> =50mA   | -      | 1.3  | 1.6  | V     |
|                              | Reverse current                      |           | I <sub>R</sub>       | V <sub>R</sub> =5V   | -      | -    | 10   | μΑ    |
| Output characteristics       | Dark current                         |           | I <sub>CEO</sub>     | V <sub>CE</sub> =10V   | -      | -    | 0.5  | μА    |
|                              | Peak sensitivity wavelength          |           | $\lambda_{p}$        | -  | -      | 800  | -    | nm    |
| Transfer<br>characteristics  | Collector current                    |           | I <sub>C</sub>       | V <sub>CE</sub> =5V, I <sub>F</sub> =20mA  | 0.45   | -    | 4.95 | mA    |
|                              | Collector-emitter saturation voltage |           | V <sub>CE(sat)</sub> | I <sub>F</sub> =20mA, I <sub>C</sub> =0.1mA  | -      | -    | 0.4  | V     |
|                              | Response time                        | Rise time | tr                   | $V_{CC}$ =5V, I <sub>F</sub> =20mA, R <sub>L</sub> =100 $\Omega$   | 1      | 10   | -    | μS    |
|                              |                                      | Fall time | tf                   |  | ı      | 10   | -    | μS    |
| Collector<br>rank            | А                                    |           | I <sub>C</sub>       | $V_{CE} = 5V, I_F = 20mA$  | 0.45   | ı    | 2.33 | m A   |
|                              | В                                    |           | IC.                  | V CE -5 V, IF-2011/A   | 0.95   | ı    | 4.95 | mA mA |
| Infrared light emitter diode | Cut-off frequency                    |           | f <sub>C</sub>       | I <sub>F</sub> =50mA * Non-coherent Infrared light emitting diode used.  | ı      | 1    | ı    | MHz   |
|                              | Peak light emitting wavelength       |           | $\lambda_{p}$        |  | -      | 950  | -    | nm    |
| Photo<br>transistor          | Response time                        |           | tr∙tf                | V <sub>CC</sub> =5V, I <sub>C</sub> =1mA, R <sub>L</sub> =100Ω *This product is not designed to be protected against electromagnetic wave. | -      | 10   | -    | μS    |
|                              | Maximum sensitivity wavelength       |           | $\lambda_{p}$        | -  | -      | 800  | -    | nm    |

#### •Electrical and optical characteristics curves

Fig.1 Relative Output Current vs.Distance (I)

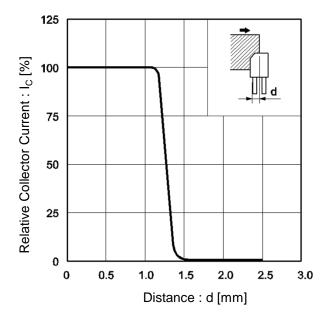


Fig.2 Relative Output Current vs.Distance (II)

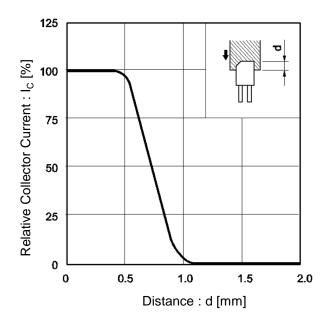


Fig.3 Forward Current Falloff

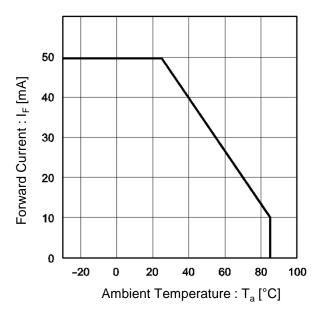
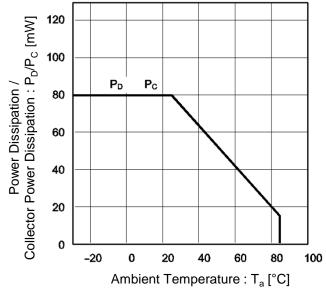


Fig.4 Power Dissipation / Collector Power Dissipation vs. Ambient Temperature



#### •Electrical and optical characteristics curves

Fig.5 Forward Current vs. Forward Voltage

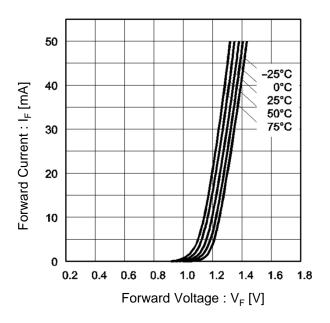


Fig.6 Collector Current vs. Forward Current

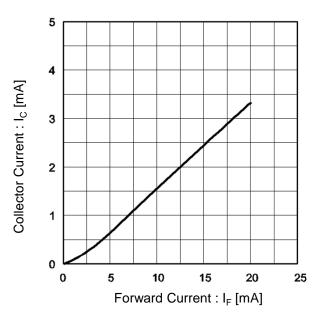


Fig.7 Relative Output vs. Ambient Temperature

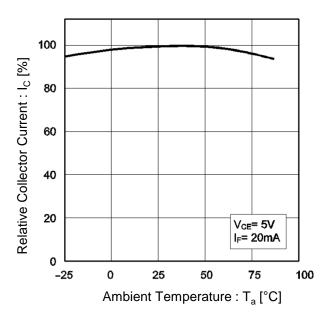
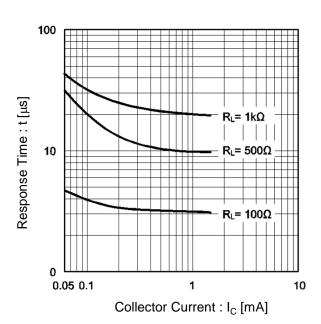


Fig.8 Response Time vs. Collector Current



#### •Electrical and optical characteristics curves

Fig.9 Dark Current vs. Ambient Temperature

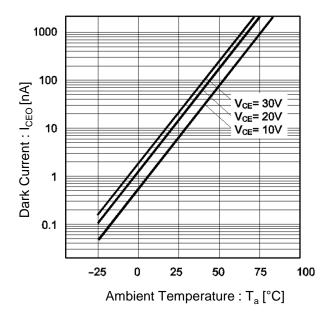


Fig.10 Output Characteristics

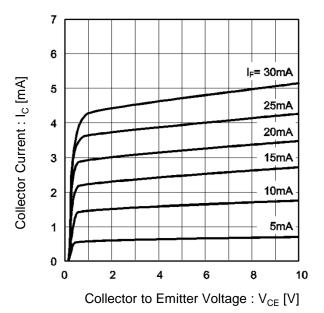
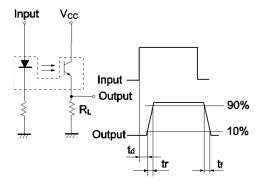


Fig.11 Response Time Measurement Circuit



 $t_d$ : Delay time

 $t_r$ : Rise time (time for output current to rise from 10% to 90% of peak current)  $t_f$ : Fall time (time for output current to fall from 90% to 10% of peak current)

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